

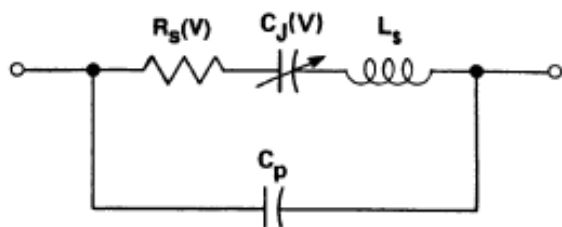
### Features

- Constant Gamma = 1.0, 1.25 & 1.5
- High Q (up to 4000 at -4 Volts)
- More Linear Frequency Tuning
- High and Nearly Constant Modulation Sensitivity
- Lead-Free (RoHS Compliant) equivalents available with 260°C reflow compatibility

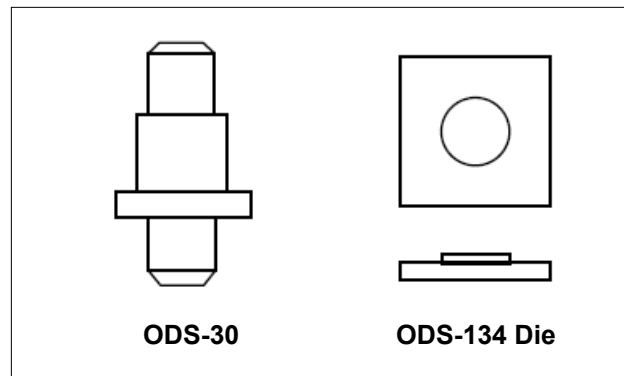
### Description and Applications

The MA46450, MA46470 and MA46410 series of tuning varactors are hyperabrupt junction Gallium Arsenide diodes featuring constant gamma 1.0 (MA46450 series), 1.25 (MA46470 series) & 1.5 (MA46410 series). These diodes offer high Q (up to 4000) permitting excellent tuning performance from VHF through Ka band. Each part in this series exhibits the large change in capacitance versus bias voltage characteristic of hyperabrupt junctions. The standard capacitance tolerance is  $\pm 10\%$ , with tighter tolerances available. Capacitance matching at one or more bias voltages is also available. All diode types are available in a wide selection of ceramic packages and in chip form. The constant gamma value of 1.0, 1.25 & 1.5 available with these diodes enables the circuit designer to produce significant improvements in circuit performance. Constant gamma tuning varactors permit more linear VCO frequency tuning than do conventional hyperabrupt tuning varactors. These varactors are particularly well suited for use in voltage tuned filters, analog phase shifters, and modulator circuits.

### Packaged Tuning Varactor Equivalent Circuit



### Common Case Styles

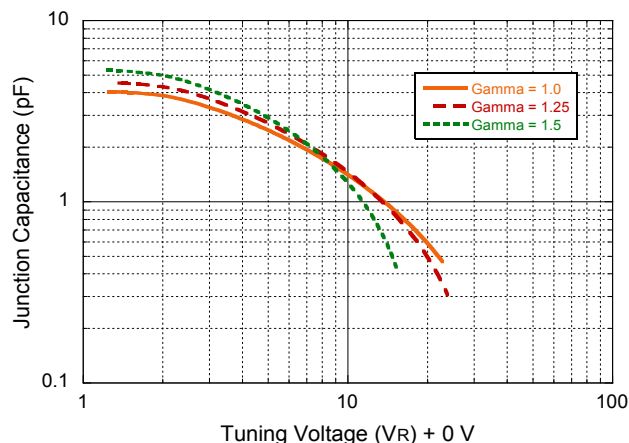


### Absolute Maximum Ratings<sup>1</sup> @ T<sub>A</sub> = +25 °C (Unless Otherwise Noted)

| Parameter             | Absolute Maximum  |
|-----------------------|-------------------|
| Reverse Voltage       | Breakdown Voltage |
| Operating Temperature | -65°C to +175°C   |
| Storage Temperature   | 65°C to +200°C    |

1. Operation of this device above any one of these parameters may cause permanent damage. The maximum storage and operating temperature of the plastic ODS-1088 case style is 125°C.

### Typical Junction Capacitance vs. Tuning Voltage



## GaAs Hyperabrupt Varactor Diode Gamma = 1.0, 1.25, & 1.5

Rev. V7

### Electrical Specifications<sup>2</sup>: T<sub>A</sub> = +25°C

#### Gamma = 1.0<sup>3</sup> MA46450 Series

Gamma = 0.9 - 1.1, V<sub>R</sub> = 2 - 20 Volts  
Junction Capacitance Ratio (C<sub>J2</sub>/C<sub>J20</sub>) = 5.0 - 8.0  
Breakdown Voltage @ I<sub>R</sub> = 10 μA, V<sub>b</sub> = 22 V min.  
Reverse Leakage Current @ V<sub>R</sub> = 18 V, I<sub>R</sub> = 100 nA max.

| Part Number | Total Capacitance<br>+/-10% <sup>4,5,6,7</sup> | Total Capacitance Ratio <sup>7</sup> | Q Minimum                          |
|-------------|--|--------------------------------------|------------------------------------|
|             | V <sub>R</sub> = 4 V<br>f = 1 MHz              | V <sub>R</sub> = 2 V / 20 V          | V <sub>R</sub> = 4 V<br>f = 50 MHz |
|             | (pF)   | -                                    | -                                  |
| MA46450     | 0.5  | 2.0-3.8                              | 4000                               |
| MA46451     | 0.7  | 2.9-4.4                              | 4000                               |
| MA46452     | 1.0  | 3.6-5.2                              | 3000                               |
| MA46457     | 2.2  | 4.1-6.1                              | 3000                               |
| MA46461     | 4.7  | 4.8-7.2                              | 1500                               |

#### Gamma = 1.25<sup>3</sup> MA46470 thru MA46485 Series

Gamma = 1.13 - 1.38, V<sub>R</sub> = 2 - 20 Volts  
Junction Capacitance Ratio (C<sub>J2</sub>/C<sub>J20</sub>) = 8.15 - 12.99  
Breakdown Voltage @ I<sub>R</sub> = 10 μA, V<sub>b</sub> = 22 V min.  
Reverse Leakage Current @ V<sub>R</sub> = 18 V, I<sub>R</sub> = 100 nA max.

| Part Number          | Total Capacitance<br>+/-10% <sup>4,5,6,7</sup> | Total Capacitance Ratio <sup>7</sup> | Q Minimum                          |
|----------------------|--|--------------------------------------|------------------------------------|
|                      | V <sub>R</sub> = 4 V<br>f = 1 MHz              | V <sub>R</sub> = 2 V / 20 V          | V <sub>R</sub> = 4 V<br>f = 50 MHz |
|                      | (pF)   | -                                    | -                                  |
| MA46470              | 0.5  | 2.2-4.1                              | 4000                               |
| MA46471              | 0.7  | 3.6-5.6                              | 4000                               |
| MA46472              | 1.0  | 4.8-7.4                              | 3000                               |
| MA46473              | 1.2  | 4.8-7.4                              | 3000                               |
| MA46474              | 1.5  | 5.0-7.4                              | 3000                               |
| MA46475              | 1.8  | 6.6-8.7                              | 3000                               |
| MA46476              | 2.0  | 6.6-8.7                              | 3000                               |
| MA46477              | 2.2  | 6.6-8.7                              | 3000                               |
| MA46479 <sup>8</sup> | 3.3  | 6.4-10.0                             | 2000                               |
| MA46480              | 3.7  | 6.8-11.0                             | 2000                               |
| MA46481              | 4.7  | 6.9-11.1                             | 1500                               |
| MA46483              | 6.8  | 7.2-11.5                             | 1500                               |
| MA46485              | 10.0   | 7.5-12.0                             | 1500                               |

#### Gamma = 1.5<sup>3</sup> MA46410 thru MA46425 Series

Gamma = 1.4 - 1.6 VR = 2 - 12 Volts  
Junction Capacitance Ratio (C<sub>J2</sub>/C<sub>J12</sub>) = 6.2 - 10.8  
Breakdown Voltage @ I<sub>R</sub> = 10 μA, V<sub>b</sub> = 18 V min.  
Reverse Leakage Current @ V<sub>R</sub> = 10 V, I<sub>R</sub> = 100 nA max.

| Part Number | Total Capacitance<br>+/-10% <sup>4,5,6,7</sup> | Total Capacitance Ratio <sup>7</sup> | Q Minimum                          |
|-------------|--|--------------------------------------|------------------------------------|
|             | V <sub>R</sub> = 4 V<br>f = 1 MHz              | V <sub>R</sub> = 2 V / 12 V          | V <sub>R</sub> = 4 V<br>f = 50 MHz |
|             | (pF)   | -                                    | -                                  |
| MA46410     | 0.30-0.43                                      | 2.7-4.3                              | 3000                               |
| MA46413     | 0.90-1.10                                      | 4.2-5.7                              | 2500                               |
| MA46416     | 1.62-1.98                                      | 5.2-4.9                              | 2500                               |
| MA46418     | 2.42-2.97                                      | 5.7-7.6                              | 1800                               |
| MA46425     | 9.00-11.00                                     | 6.6-8.8                              | 1200                               |

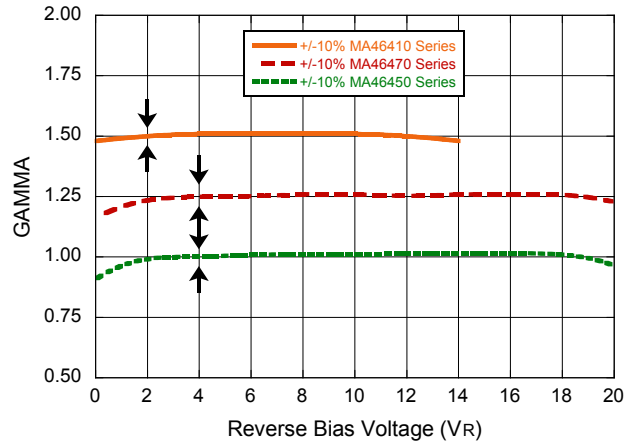
- All GaAs tuning varactors are available in chip form. Please contact factory for part number information.
- The values guaranteed for gamma are measured on unpackaged chips. The total capacitance versus bias voltage curve will deviate slightly from the chip capacitance versus bias voltage curve due to the package parasitic capacitance (C<sub>p</sub>).
- Case parasitics (C<sub>p</sub> and L<sub>s</sub>) are given for most case styles along with case outlines in the appendix.
- Closer tolerances are available upon request.
- Reverse voltage (V<sub>br</sub>) is measured at 10 microamps.
- The total capacitance and capacitance ratios shown are for diodes housed in case style 30 with C<sub>p</sub> = 0.170 pF unless otherwise specified. Other case styles will result in different values.
- This part is offered in die form, shipped in a gel pack. The part number is MAVR-046479-01340G.

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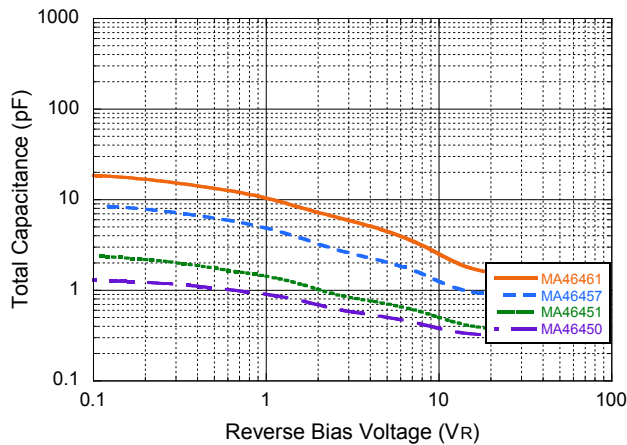
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## Typical Performance Curves

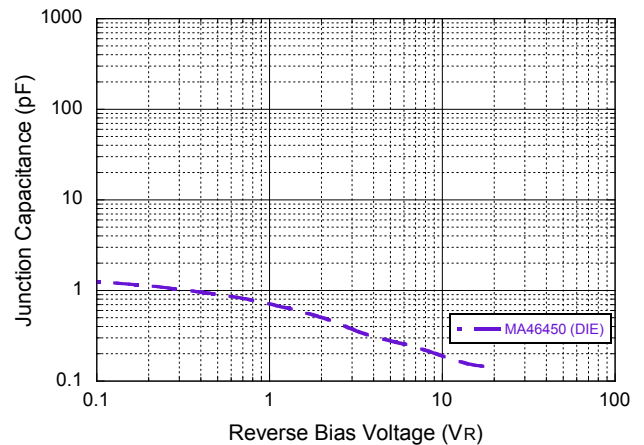
**Gamma vs. Reverse Bias Voltage**



**Gamma = 1.0**  
**Total Capacitance vs. Reverse Bias Voltage**  
*(Packaged parts in case style ODS-30)*



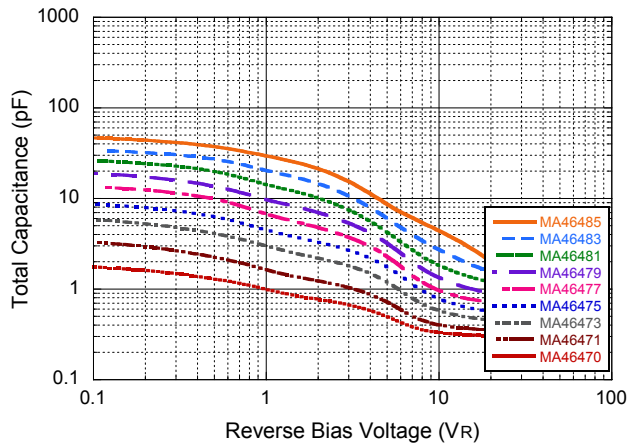
**Gamma = 1.0**  
**Junction Capacitance vs. Reverse Bias Voltage**  
*(DIE)*



## Typical Performance Curves

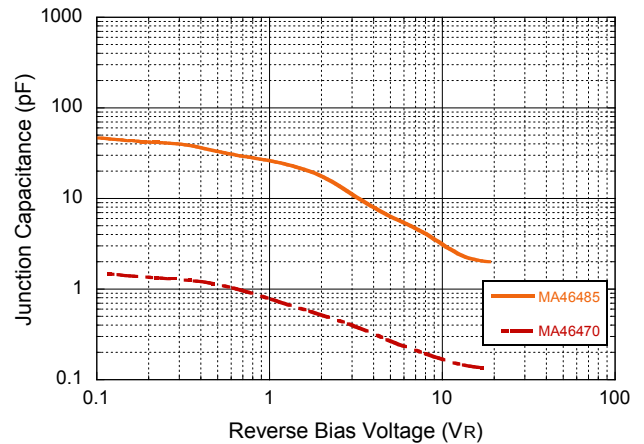
**Gamma = 1.25**

**Total Capacitance vs. Reverse Bias Voltage**  
*(Packaged parts in case style ODS-30)*



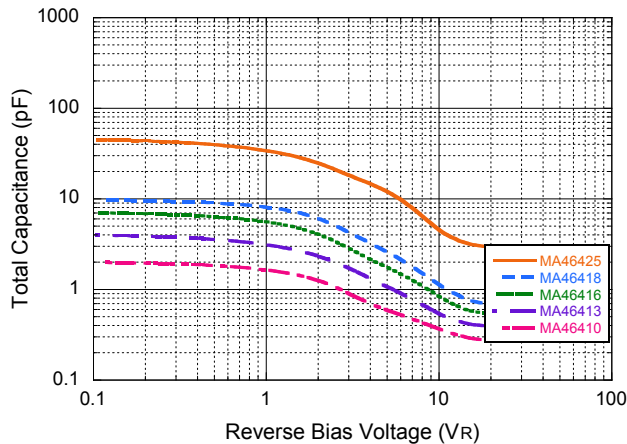
**Gamma = 1.25**

**Junction Capacitance vs. Reverse Bias Voltage**  
*(DIE)*



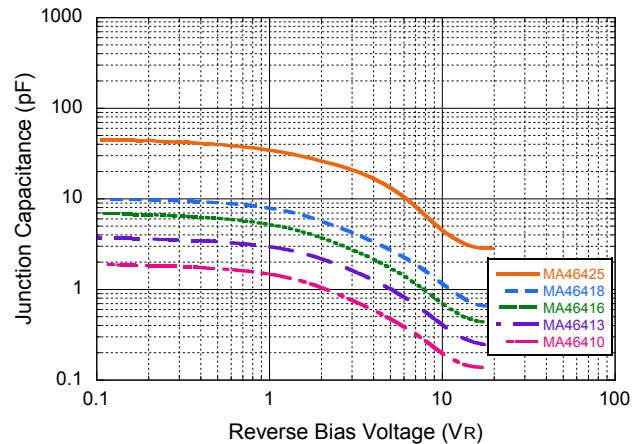
**Gamma = 1.5**

**Total Capacitance vs. Reverse Bias Voltage**  
*(Packaged parts in case style ODS-30)*



**Gamma = 1.5**

**Junction Capacitance vs. Reverse Bias Voltage**  
*(DIE)*



# MA46410 thru MA46480 Series



GaAs Hyperabrupt Varactor Diode  
Gamma = 1.0, 1.25, & 1.5

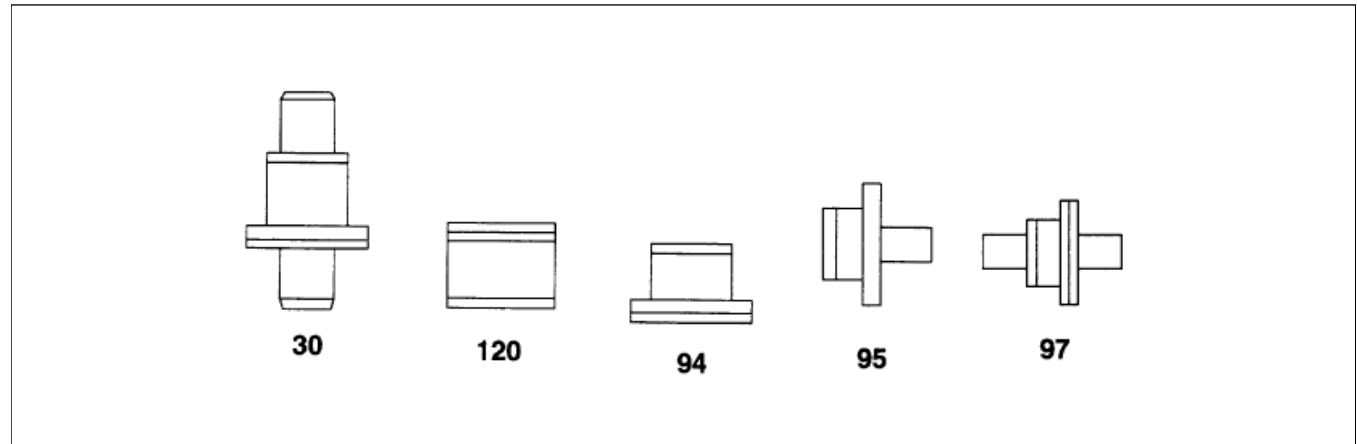
Rev. V7

## Environmental Ratings per MIL-STD-750

| Parameter           | Method | Level                        |
|---------------------|--------|------------------------------|
| Storage Temperature | 1031   | See Absolute Maximum Ratings |
| Temperature Cycle   | 1051   | 10 cycles, -65°C to +175°C   |
| Shock               | 2016   | 500 g's                      |
| Vibration           | 2056   | 15 g's                       |

## Case Styles (Dimensions are available upon request)

### Typical Coaxial Packages



### Typical Coplanar Packages

